PIC 部分问题

Vhaleking

Q1: Compare the following materials from 4 aspects

- 1. LiNbO3
- 2. Submicron silicon photonics
- 3. Silica on silicon
- 4. Polymers
 - a) Operating wavelengths
 - b) Index contrast
 - c) Capability to integrate the light source
 - d) Capability to make fast modulators

Q3: How to define the TE and TM polarisations in the waveguide and explain its effect on the losses.

Q5: Write down the complete design flow and explain

Q6: Compare these modulation methods from 4 aspects

- 1. Carrier
- 2. Thermal
- 3. Liquid crystals
- 4. Franz-Keldysh effect (或量子受限斯塔克效应)
 - a) Strength
 - b) Speed
 - c) Power consumption
 - d) Applicability

Q11: Explain what is an echelle grating. Why is it lossy due to its inner structures?

Q13: How can you unintentionally have the coupling between clockwise propagating modes and counter-clockwise propagating modes in a ring resonator? What will the spectrum be like?

Q16: In what fabrication processes there will be some variability? Which kind of variability patterns do people typically identify? Give one example of during which process we can have the following variability.

- 1. Long-range radial thickness variation
- 2. Line-width variation with the change of pattern density
- 3. Waveguide-width variation on different dies on the wafer.